

ESH1PB, ESH1PC, ESH1PD

Vishay General Semiconductor

High Current Density Surface Mount Ultrafast Rectifiers



DO-220AA (SMP)

PRIMARY CHARACTERISTICS					
I _{F(AV)}	1.0 A				
V _{RRM}	100 V, 150 V, 200 V				
t _{rr}	25 ns				
V _F	0.90 V				
T _J max.	175 °C				

TYPICAL APPLICATIONS

For use in secondary rectification and freewheeling for ultrafast switching speeds of AC/AC and DC/DC converters in high temperature conditions for both consumer and automotive applications.

Operating junction and storage temperature range

FEATURES

- Very low profile typical height of 1.0 mm
- · Ideal for automated placement
- · Glass passivated chip junction
- Ultrafast recovery times for high frequency
- · Low forward voltage drop, low power loss
- · Low thermal resistance
- Meets MSL level 1 per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

MECHANICAL DATA

Case: DO-220AA (SMP)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS compliant, and

commercial grade

Base P/NHM3 - halogen-free, RoHS compliant, and automotive grade

Terminals: Matte tin plated leads, solderable J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix

meets JESD 201 class 2 whisker test Polarity: Color band denotes cathode end

- 55 to + 175

MAXIMUM RATINGS (T_A = 25 °C unless otherwise noted) **PARAMETER SYMBOL ESH1PB ESH1PC ESH1PD** UNIT РΒ PC PD Device marking code ٧ Maximum repetitive peak reverse voltage 100 150 200 V_{RRM} Maximum average forward rectified current (fig. 1) 1.0 I_{F(AV)} Peak forward surge current 10 ms single 50 Α I_{FSM} half sine-wave superimposed on rated load

T_J, T_{STG}







FREE

°C

ESH1PB, ESH1PC, ESH1PD

Vishay General Semiconductor



ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT			
Maximum instantaneous forward voltage	I _F = 0.7 A	T _J = 25 °C	V _F ⁽¹⁾	0.86	V			
	I _F = 1 A			0.90				
Maximum roverse current at rated V- voltage	T _J = 25 °C	T _J = 25 °C	I _R ⁽²⁾	1.0	μΑ			
Maximum reverse current at rated V _R voltage		T _J = 125 °C		25				
Maximum reverse current	V _R = 20 V	T _J = 150 °C	I _R	50	μΑ			
Maximum reverse recovery time	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A		t _{rr}	25	ns			
Typical reverse recovery time	$I_F = 1.0 \text{ A}, V_R = 30 \text{ V},$ $dI/dt = 50 \text{ A/}\mu\text{s}, I_{rr} = 10 \% I_{RM}$	T _J = 25 °C	- t _{rr}	25	- ns			
		T _J = 100 °C		35				
Typical stored charge	$I_F = 1.0 \text{ A}, V_R = 30 \text{ V},$ $dI/dt = 50 \text{ A/}\mu\text{s}, I_{rr} = 10 \% I_{RM}$	T _J = 25 °C	Q _{rr}	10	nC			
		T _J = 100 °C		15				
Typical junction capacitance	4.0 V, 1 MHz		CJ	25	pF			

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
ESH1PB-M3/84A	0.024	84A	3000	7" diameter plastic tape and reel			
ESH1PB-M3/85A	0.024	85A	10 000	13" diameter plastic tape and reel			
ESH1PBHM3/84A (1)	0.024	84A	3000	7" diameter plastic tape and reel			
ESH1PBHM3/85A (1)	0.024	85A	10 000	13" diameter plastic tape and reel			

Note

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

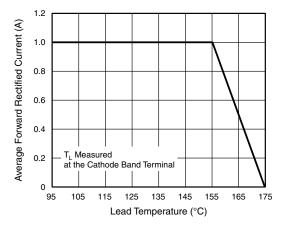


Fig. 1 - Forward Current Derating Curve

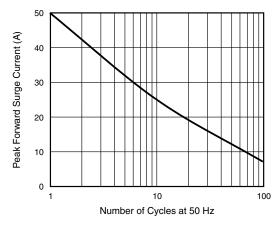


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

⁽¹⁾ Automotive grade



ESH1PB, ESH1PC, ESH1PD

Vishay General Semiconductor

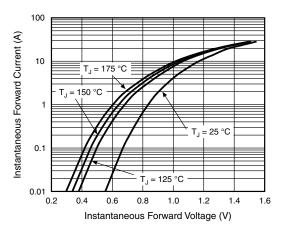


Fig. 3 - Typical Instantaneous Forward Characteristics

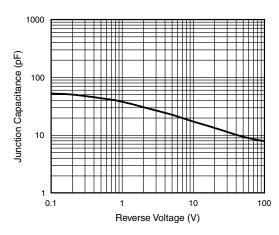


Fig. 5 - Typical Junction Capacitance

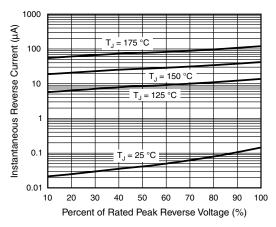


Fig. 4 - Typical Reverse Leakage Characteristics

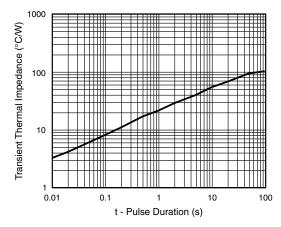
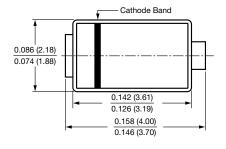
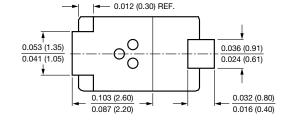


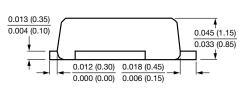
Fig. 6 - Typical Transient Thermal Impedance

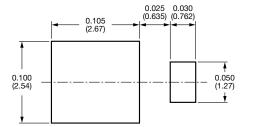
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

DO-220AA (SMP)









Document Number: 88895 Revision: 19-Apr-11

For technical questions within your region, please contact one of the following: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000